

Phase Control Thyristor Type SA22ZY2015A0

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Date: November, 2020
Data Sheet Issue: 1



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SA	22	ZY	2015	A	0	
-	Voltage Code	Outline Code	Current code	Type code	Special code	Optional code

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Absolute Maximum Ratings

VOLTAGE RATINGS		MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	2200	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	2200	V
V_{DDC}	Maximum DC of-state voltage, (note 1)	1350	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2200	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2300	V
V_{RDC}	Maximum DC revrese voltage, (note 1)	1350	V
note 1)	De-rating factor of 0.13%/°C is applicable for T_j below 25°C		

OTHER RATINGS		MAXIMUM LIMITS	UNITS
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 55^{\circ}C$, (note 1)	2015	A
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 85^{\circ}C$, (note 1)	1385	A
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 85^{\circ}C$, (note 2)	775	A
$I_{T(RMS)M}$	Nominal RMS on-state current, $T_{sink} = 25^{\circ}C$ (note 1)	3975	A
$I_{T(d.c.)}$	D.C. on-state current, $T_{sink} = 25^{\circ}C$, (note 3)	3455	A
I_{TSM}	Peak non-repetitive surge current $t_p = 10ms$, $V_{RM} = 60\%V_{RRM}$, (note 4)	32.4	kA
I_{TSM2}	Peak non-repetitive surge current $t_p = 10ms$, $V_{RM} \leq 10V$, (note 4)	35.7	kA
I^2t	I^2t capacity for fusing $t_p = 10ms$, $V_{RM} = 60\%V_{RRM}$, (note 4)	$5.25 \cdot 10^6$	A ² s
I^2t	I^2t capacity for fusing $t_p = 10ms$, $V_{RM} \leq 10V$, (note 4)	$6.37 \cdot 10^6$	A ² s
$(di/dt)_{cr}$	Critical rate of rise of on-state current (continuous, 50Hz), (note 5)	100	A/ μ s
	Critical rate of rise of on-state current (repetitive, 50Hz, 60s), (note 5)	200	A/ μ s
	Critical rate of rise of on-state current (non repetitive), (note 5)	400	A/ μ s
V_{RGM}	Peak reverse gate voltage	5	V
$P_{G(AV)}$	Mean forward gate power	4	W
P_{GM}	Peak forward gate power	30	W
T_{jop}	Operating temperature range	-40 to +125	°C
T_{stg}	Storage temperature range	-40 to +150	°C
note 1)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 2)	Single-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 3)	Double-side cooled		
note 4)	Half-sinewave, 125°C T_j initial		
note 5)	$V_D = 67\%V_{DRM}$, $I_{TM} = 2000A$, $I_{FG} = 2A$, $t_R \leq 0.5\mu s$, $T_{case} = 125^{\circ}C$		

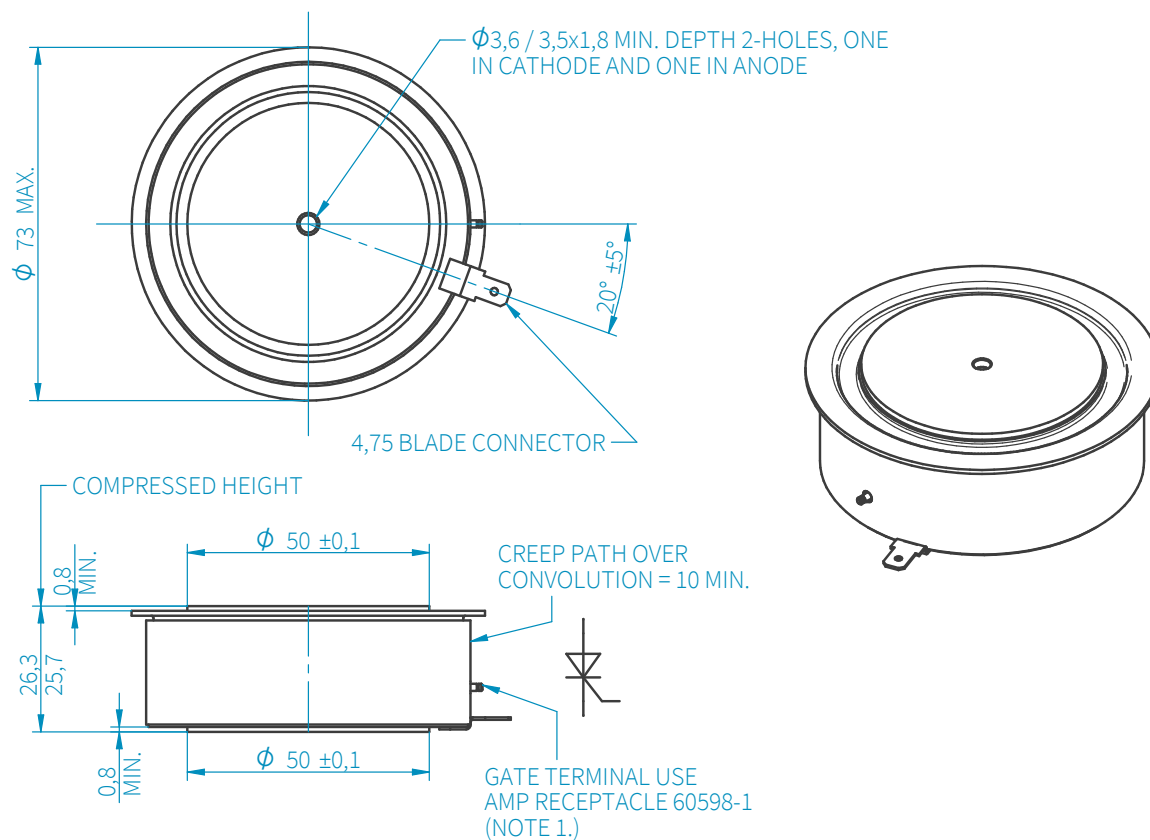
Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V_{TM}	Maximum peak on-state voltage	$I_{TM} = 3000A$	-	-	1.50	V
		$I_{TM} = 7200A$	-	-	2.40	V
V_{T0}	Threshold voltage		-	-	0.883	V
r_T	Slope resistance		-	-	0.210	mΩ
$(dv/dt)_{CR}$	Critical rate of rise of off-state voltage	$V_D = 80\%V_{DRM}$, Linear ramp, gate o/c	1000	-	-	V/μs
I_{DRM}	Peak off-state current	Rated V_{DRM}	-	-	100	mA
I_{RRM}	Peak reverse current	Rated V_{RRM}	-	-	100	mA
V_{GT}	Gate trigger voltage	$T_j = 25^\circ C$, $V_D = 10V$, $I_T = 3A$	-	-	3.0	V
I_{GT}	Gate trigger current		-	-	300	mA
V_{GD}	Gate non-trigger voltage	Rated V_{DRM}	-	-	0.25	V
I_H	Holding current	$T_j = 25^\circ C$	-	-	1000	mA
t_{GD}	Gate controlled turn-on delay time	$V_D = 67\%V_{DRM}$, $I_{TM} = 2000A$, $di/dt = 10A/\mu s$,	-	0.8	2.0	μs
t_{GT}	Turn-on time	$I_{FG} = 2A$, $t_r = 0.5\mu s$, $T_j = 25^\circ C$	-	1.4	3.0	μs
Q_{RR}	Recovered charge		-	4000	-	μC
Q_{RA}	Recovered charge, 50% Chord	$I_{TM} = 1000A$, $t_p = 1000\mu s$, $di/dt = 10A/\mu s$, $V_R = 50V$	-	2300	2600	μC
I_{RR}	Reverse recovery current		-	155	-	A
t_{RR}	Reverse recovery time, 50% Chord		-	30	-	μs
t_{GQ}	Turn-off time	$I_{TM} = 1000A$, $t_p = 1000\mu s$, $di/dt = 10A/\mu s$, $V_R = 50V$, $V_{DR} = 80\%V_{DRM}$, $dV_{DR}/dt = 20V/\mu s$	-	375	-	μs
		$I_{TM} = 1000A$, $t_p = 1000\mu s$, $di/dt = 10A/\mu s$, $V_R = 50V$, $V_{DR} = 80\%V_{DRM}$, $dV_{DR}/dt = 200V/\mu s$	-	650	-	μs
R_{thJK}	Thermal resistance, junction to sink	Double-side cooled	-	-	18	K/kW
		Anode-side cooled	-	-	33	K/kW
		Cathode-side cooled	-	-	40	K/kW
F	Mounting force	(note 2)	25	-	31	kN
W_t	Weight		-	550	-	g
note 1)	Unless otherwise indicated $T_j = 125^\circ C$					
note 2)	For other clamp forces, please consult factory					

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